

## Erratum to: Nonlinear optical properties of asymmetric n-type double $\delta$ -doped GaAs quantum well under intense laser field<sup>\*</sup>

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The form of the parameters  $\alpha$  and  $z_o$  defined in equation (2) are mistyped in the original article. The correct version of these parameters is given below:

$$\alpha = \frac{e^2(2m^*)^{3/2}}{15\pi\epsilon\hbar^3}, \quad z_{oL} = \left( \frac{2\epsilon\alpha^3}{\pi e^2 N_{2d}^L} \right)^{1/5}, \quad z_{oR} = \left( \frac{2\epsilon\alpha^3}{\pi e^2 N_{2d}^R} \right)^{1/5}$$

<sup>\*</sup> The online version of the original article can be found at <https://doi.org/10.1140/epjb/e2017-80210-9>.

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